- Inputs Are TTL-Voltage Compatible
- Permits Multiplexing From N Lines to One Line
- Performs Parallel-to-Serial Conversion
- Strobe (Enable) Line Provided for Cascading (N Lines to N Lines)
- Flow-Through Architecture Optimizes
 PCB Layout
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages and Standard Plastic 300-mil DIPs

description

This data selector/multiplexer contains inverters and drivers to supply full binary decoding data selection to the AND-OR gates. Separate strobe inputs (\overline{G}) are provided for each of the two four-line sections.

The 74ACT11153 is characterized for operation from – 40°C to 85°C.

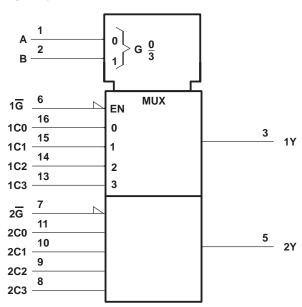
FUNCTION TABLE

SELECT INPUTS			DATA I	NPUT	S	STROBE	OUTPUT		
В	Α	C0	C1	C2	C3				
Х	Χ	Х	Χ	Χ	Χ	Н	L		
L	L	L	Χ	Χ	Χ	L	L		
L	L	Н	Χ	Χ	Χ	L	Н		
L	Н	Х	L	Χ	Χ	L	L		
L	Н	Х	Н	Χ	Χ	L	Н		
Н	L	Х	Χ	L	Χ	L	L		
Н	L	Х	Χ	Н	Χ	L	Н		
Н	Н	Х	Χ	Χ	L	L	L		
Н	Н	Х	Х	Х	Н	L	Н		

H = high level, L = low level, X = irrelevant

DORNPACKAGE (TOP VIEW) Α 16 1C0 вП 15 1 1C1 14 1C2 1Y **∏** GND [13 1C3 2Y 👖 12 VCC 1<u>G</u> [11 2C0 2<u>G</u> ∏ 10 1 2C1 2C3 **∏** 9 7 2C2

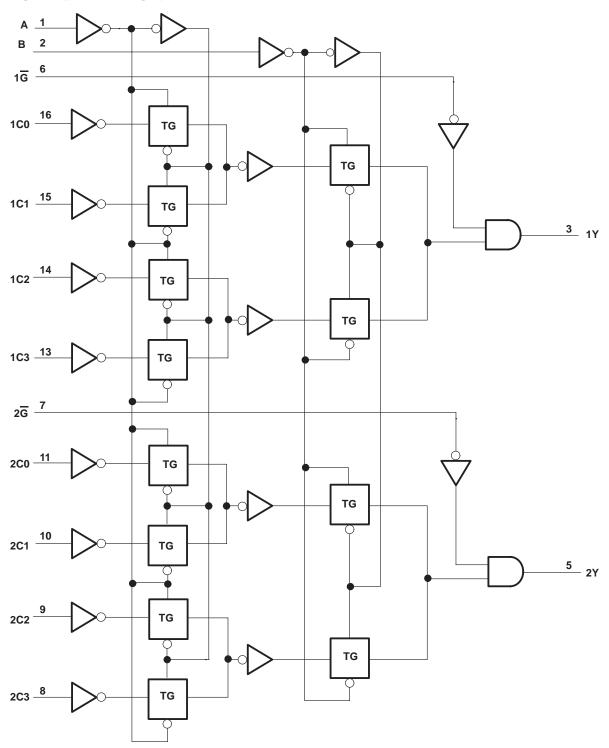
logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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logic diagram (positive logic)





SCAS118A - D3583, JUNE 1990 - REVISED APRIL 1993

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	-0.5 V to V _{CC} + 0.5 V
Output voltage range, V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	± 20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	$\dots \dots \pm 50 \text{ mA}$
Continuous output current, I_O ($V_O = 0$ to V_{CC})	± 50 mA
Continuous current through V _{CC} or GND	
Storage temperature range	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		V
V _{IL}	Low-level input voltage		0.8	V
٧ _I	Input voltage	0	VCC	V
٧o	Output voltage	0	VCC	V
ЮН	High-level output current		-24	mA
lOL	Low-level output current		24	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T _A	Operating free-air temperature	- 40	85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T _A = 25°C			MINI	MAY	LINUT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	UNIT
	Jan. 50 A	4.5 V	4.4			4.4		
	ΙΟΗ = – 50 μΑ		5.4			5.4		
VOH	I _{OH} = – 24 mA		3.94			3.8		V
			4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V				3.85		
	Ι _{ΟL} = 50 μΑ				0.1		0.1	
VoL	10[= 30 μΑ	5.5 V			0.1		0.1	
	I _{OL} = 24 mA	4.5 V			0.36		0.44	V
		5.5 V			0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V					1.65	
l _l	$V_I = V_{CC}$ or GND	5.5 V			± 0.1		±1	μΑ
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			8		80	μΑ
∆lcc [‡]	One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V			0.9		1	mA
Ci	$V_I = V_{CC}$ or GND	5 V		3.5				pF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

[‡] This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.



NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

SCAS118A - D3583, JUNE 1990 - REVISED APRIL 1993

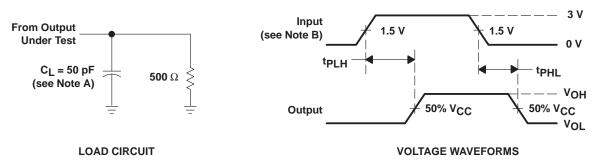
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T _A = 25°C			MIN	MAX	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	"""	IVIAA	ONIT
t _{PLH}	A or B	Y	2.8	6.4	9.8	2.8	10.9	ns
t _{PHL}			3.1	6.8	10	3.1	11	
t _{PLH}	Data (Any C)	~	2.8	5.4	7.5	2.8	8.3	ns
t _{PHL}		'	3	6.4	8.8	3	9.8	115
t _{PLH}	G	~	2.2	5.5	8.6	2.2	9.3	nc
t _{PHL}		r	2.9	5.6	6.6	2.9	7.6	ns

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	34	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f = 3$ ns. $t_f = 3$ ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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